## NSN 5961-00-734-7426

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-734-7426 **Inclosure Material:** Metal **Overall Length:** 0.250 inches **Terminal Length:** 0.250 inches **Overall Diameter:** 0.230 inches **Function For Which Designed:** Amplifier **Internal Configuration:** Junction contact **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 20.0 collector to base voltage/static/emitter open and 12.0 collector to emitter voltage/static/base open and 2.5 emitter to base voltage, static, collector open **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 80063-sm-a-696863 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**